NSN 5962-01-453-8888

Digital Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

420.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

1055-01-256-9756

Features Provided:

Monolithic and 3-state output and bipolar

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Bipolar metal-oxide semiconductor

Design Function And Quantity:

1 transceiver

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, digital, advanced bipolar cmos, scan test device with octal bus transceiver with three-state outputs, ttl compatible inputs, monolithic silicon

Voltage Rating And Type Per Characteristic:

-0.5 volts input and 7.0 volts input

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A458a0